**PATENT** 

## THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

Bong-Cheol Kim

Serial No.

10/089,479

Filed

March 28, 2002

Group AFF Unit: 2812

For

APPARATUS AND METHOD FOR FORMING SINGLE CRYSTALLINE

NITRIDE SUBSTRATE USING HYDRIDE VAPOR PHASE EPITAXY

AND LASER BEAM

REQUEST FOR A CORRECTED OFFICIAL FILING RECEIPT

**Assistant Commissioner for Patents** Office of Initial Patent Examination Customer Service Center Washington, D.C. 20231

Sir:

We have received the Official Filing Receipt for the application identified above. On the Official Filing Receipt, we noted an error in the title of the invention. Please correct as follows:

--APPARATUS AND METHOD FOR FORMING SINGLE

CRYSTALLINE NITRIDE SUBSTRATE USING HYDRIDE VAPOR PHASE EPITAXY

AND LASER BEAM--.

Applicant hereby respectfully requests the issuance of a corrected Official Filing Receipt.

Respectfully submitted,

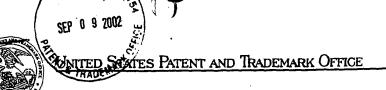
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COMMISSIONER FOR PATENTS
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WASHINGTON, D.C. 2023I
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 APPLICATION NUMBER
 FILING DATE
 GRP ART UNIT
 FIL FEE REC'D
 ATTY.DOCKET.NO
 DRAWINGS
 TOT CLAIMS
 IND CLAIMS

 10/089,479
 03/28/2002
 2812
 520
 A35109 PCT USA
 4
 11
 2

CONFIRMATION NO. 1153

FILING RECEIPT
\*OC0000000008267496\*

21003 BAKER & BOTTS 30 ROCKEFELLER PLAZA NEW YORK, NY 10112

Date Mailed: 06/26/2002

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Bong-Cheol Kim, Cheongju-shi, JAPAN;

Domestic Priority data as claimed by applicant

THIS APPLICATION IS A 371 OF PCT/KR00/00935 08/21/2000

Foreign Applications

REPUBLIC OF KOREA 1999-41892 09/30/1999

Projected Publication Date: Not Applicable, filed prior to November 29,2000

Non-Publication Request: No

Early Publication Request: No

\*\* SMALL ENTITY \*\*

NITRIDE

Title

Apparatus and method for forming single crystalline nitrade substrate using hydride vapor phase epitaxy and laser beam

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